# NSN 5961-00-520-3453

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#### **Inclosure Material:**

Metal

**End Application:** 

Aircraft, galaxy c-5

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

## **Mounting Method:**

Terminal

## Criticality Code Justification:

Feat

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

190.0 collector to base voltage/static/emitter open and 180.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute

#### **Special Features:**

Junction pattern arrangement: npn; weapon system essential

## **Test Data Document:**

97896-341-0287 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) and 97896-341-0276 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0